

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCV373FK

Octal Schmitt D-Type Latch with 3-State Output

The TC74VHCV373FK is an advanced high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate CMOS technology.

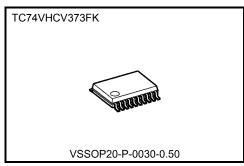
It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}).

When the $\overline{\rm OE}$ input is high, the eight outputs are in a high impedance state. Input pin have hysteresis between the positive-going and negative-going thresholds. Thus the TC74VHCV373FK are capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output $^{\rm (Note)}$ pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state



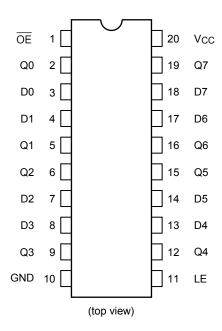
Weight VSSOP20-P-0030-0.50 : 0.03 g (typ.)

Features

- High speed: tpd = 5.4 ns (typ.) at Vcc = 5 V
- Low power dissipation: ICC = 2 μA (max) at Ta = 25°C
- Wide operating voltage range: VCC (opr) = 1.8 V to 5.5 V
- Ouput current: |IOH|/IOL = 16 mA (min) (VCC = 4.5 V)
- Available in VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 373 typ



Pin Assignment



Truth Table

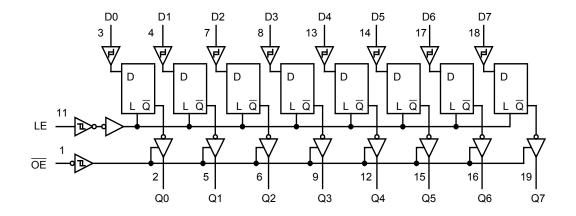
	Inputs		Output
ŌĒ	LE	D	Output
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram





Absolute Maximum Ratings (Note1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	−0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	V	-0.5 to 7.0 (Note 2)	V
DC output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	lıĸ	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	ICC/IGND	±100	mA
Storage temperature	T _{stg}	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in off-state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: VOUT < GND, VOUT > VCC

Operating Ranges (Note1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	1.8 to 5.5	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V	0 to 5.5 (Note 2)	V
Output voltage	Vout	0 to V _{CC} (Note 3)	V
Operating temperature	Topr	−40 to 85	°C
Input rise and fall time	dt/dv	0 to 20 (V _{CC} = 3.3 ± 0.3 V) 0 to 1 (V _{CC} = 5 ± 0.5 V)	ms/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: Output in off-state

Note 3: High or low state.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol Test Condition			Ta = 25°C		Ta = −40 to 85°C		Unit		
				V _{CC} (V)	Min	Тур.	Max	Min	Max	
				1.8	_	_	1.65	_	1.65	
				2.3	_	_	1.85	_	1.85	
Positive threshold voltage	VP		_	3.0	_	_	2.20	_	2.20	
				4.5	_	_	3.15	_	3.15	
				5.5	_	_	3.85	_	3.85	V
				1.8	0.15	_	_	0.15	_	
				2.3	0.45	_	_	0.45	_	
Negative threshold voltage	VN		_	3.0	0.90	_	_	0.90	_	
				4.5	1.35	_	_	1.35	_	
				5.5	1.65			1.65		
				1.8	0.15	_	1.05	0.15	1.05	
I bratanasia vraltana	V _H	_		2.3	0.20	_	1.10	0.20	1.10	V
Hysteresis voltage				3.0	0.30	_	1.20	0.30	1.20	
				4.5	0.40	_	1.40	0.40	1.40	
			<u> </u>	5.5	0.50		1.60	0.50	1.60	
	Vон	VIN = VIH or VIL	Jan. 50 A	1.8	1.7	1.8	_	1.7	_	
			IOH = −50 μA	3.0	2.9	3.0	_	2.9	_	
High-level output voltage				4.5	4.4	4.5		4.4		
			I _{OH} = -8 mA	3.0 4.5	2.58 3.94	_	_	2.48 3.80	_	
			I _{OH} = −16 mA		3.94	_	_	3.60		V
				1.8	_	0.0	0.1	_	0.1	
		VIN	I _{OL} = 50 μA	3.0	_	0.0	0.1	_	0.1	
Low-level output voltage	V _{OL}	= V _{IH} or V _{IL}		4.5	_	0.0	0.1	_	0.1	
		1111 01 112	I _{OL} = 8 mA	3.0	_	_	0.36	_	0.44	
			I _{OL} = 16 mA	4.5		_	0.44		0.55	
3-state output off-state		VIN = VIH or	VIL							
current	loz	V _{OUT} = 0 to 5.5V		1.8 to 5.5	_	_	±0.5	_	±5.0	μΑ
Power-off leakage current	loff	V _{IN} /V _{OUT} = 5.5 V		0	-	_	0.5	-	5.0	μА
Input leakage current	liN	V _{IN} = 5.5 V c	or GND	0 to 5.5	_	_	±0.1	_	±1.0	μΑ
Quiescent supply current	Icc	V _{IN} = V _{CC} or	GND	5.5	_	_	2.0	1	20.0	μΑ



Timing Requirements (input: tr = tf = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width			2.5 ± 0.2	_	6.0	6.5	
(LE)	tw (H)	_	3.3 ± 0.3	_	5.0	5.0	ns
(CL)			5.0 ± 0.5	_	5.0	5.0	
			2.5 ± 0.2	_	4.5	5.0	
Minimum set-up time	ts	_	3.3 ± 0.3	_	4.0	4.0	ns
			5.0 ± 0.5	1	4.0	4.0	
			2.5 ± 0.2	_	1.5	1.5	
Minimum hold time	th	_	3.3 ± 0.3	_	1.0	1.0	ns
			5.0 ± 0.5		1.0	1.0	



AC Electrical Characteristics (input: tr = tf = 3 ns)

Characteristics	Symbol	Tes	st Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
Silalastoriotio	Symbol		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Offic
			2.5 ± 0.2	15	_	10.7	15.7	1.0	19.0	
				50		13.5	19.3	1.0	22.0	
Propagation delay time	tpLH		00.00	15		7.4	11.0	1.0	13.0	
(LE-Q)	t _{pHL}	_	3.3 ± 0.3	50		9.5	14.5	1.0	16.5	ns
,				15	_	5.4	7.2	1.0	8.5	
			5.0 ± 0.5	50	_	7.1	9.2	1.0	10.5	
			05.00	15	_	13.0	17.7	1.0	20.1	
			2.5 ± 0.2	50		15.5	21.1	1.0	24.1	
Propagation delay time	t _{pLH}		3.3 ± 0.3	15	-	8.8	12.9	1.0	14.8	20
(D-Q)	t _{pHL}	_	3.3 ± 0.3	50	_	10.8	15.5	1.0	17.7	ns
			5.0 ± 0.5	15	1	6.2	7.2	1.0	8.5	
				50	1	8.0	9.3	1.0	10.6	
	^t pZL tpZH	R _L = 1 kΩ	2.5 ± 0.2	15	_	9.4	15.8	1.0	19.0	ns
				50	_	12.3	18.8	1.0	22.0	
3-state output enable			3.3 ± 0.3	15	_	6.5	11.4	1.0	13.5	
time				50	_	8.7	14.9	1.0	17.0	
			5.0 ± 0.5	15	_	4.5	8.1	1.0	9.5	
			3.0 ± 0.5	50	_	6.2	10.1	1.0	11.5	
	.		2.5 ± 0.2	50	_	14.5	17.4	1.0	19.0	
3-state output disable time	t _{pLZ} t _{pHZ}	$R_L = 1 k\Omega$	3.3 ± 0.3	50	_	10.9	13.2	1.0	15.0	ns
	p		5.0 ± 0.5	50	_	8.0	9.2	1.0	10.5	
	.		2.5 ± 0.2	50	_	_	1.5	_	1.5	
Output to output skew	t _{osLH} t _{osHL}	(Note 1)	3.3 ± 0.3	50	_	_	1.5	_	1.5	ns
			5.0 ± 0.5	50	_	_	1.0	_	1.0	
Input capacitance	C _{IN}		_		_	4	10	_	10	pF
Output capacitance	Cout		_		_	6	_	_	_	pF
Power dissipation capacitance	C _{PD}			(Note 2)	_	21	_	_	_	pF

Note 1: Parameter guaranteed by design.

tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|

Note 2: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

ICC (opr) = CPD·VCC·fIN + ICC/8 (per latch)

And the total CPD when n pcs. of Latch operate can be gained by the following equation:

CPD (total) = 11 + 10·n



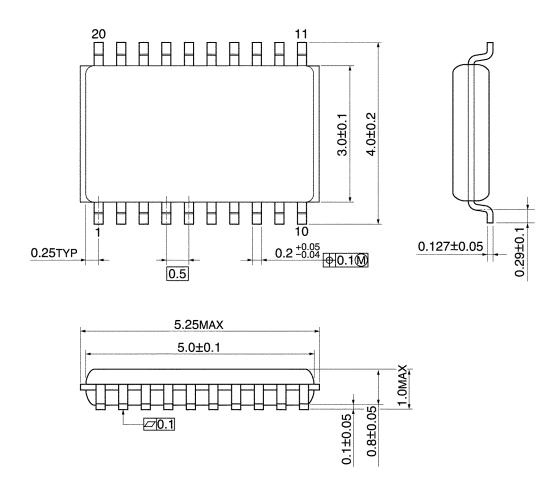
Noise Characteristics (input: tr = tf = 3 ns)

Charactaristics	Current el	Test Condition		Ta = 25°C		l lmit
Characteristics	Symbol		V _{CC} (V)	Тур.	Max	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	3.3	0.3	_	V
Quiet output maximum dynamic VOL		СL – 50 рг	5.0	0.7	ı	v l
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	3.3	-0.1	_	V
Quiet output minimum dynamic VOL		CL = 30 βi	5.0	-0.4	_	V
Minimum high level dynamic input voltage	VIHD	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	VILD	C _L = 50 pF	5.0	_	1.5	V



Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)



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